FAIRCHILD

SEMICONDUCTOR

74VCX162827

Low Voltage 20-Bit Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs and 26 Ω Series Resistors in the Outputs

General Description

The VCX162827 contains twenty non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/ receiver. The device is byte controlled. Each byte has NOR output enables for maximum control flexibility.

The 74VCX162827 is designed for low voltage (1.4V to 3.6V) V_{CC} applications with I/O capability up to 3.6V. The VCX162827 is also designed with 26Ω resistors in the outputs.

The 74VCX162827 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

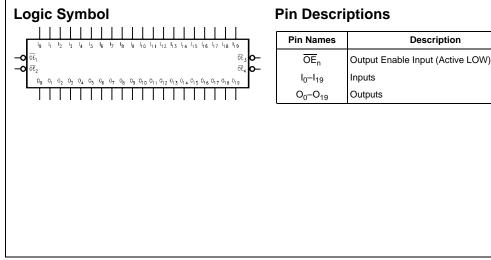
Features

- 1.4V-3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD}
- 3.4 ns max for 3.0V to 3.6V $\rm V_{\rm CC}$
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL}) ±12 mA @ 3.0V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance: Human body model > 2000V
 - Machine model > 200V

Note 1: To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description				
74VCX162827MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide				
Devices also available in	Devices also available in Tape and Reel. Specify by appending the suffix "X" to the ordering code.					



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74VCX162827

Connection Diagram						
	56 - 0E ₂					
2	55 - 1 ₀					
3	54 - I					
4	53 — GND					
5	52 - I ₂					
6	51 - I ₃					
7	50 — V _{CC}					
8	49 I ₄					
9	48 — I ₅					
10	47 – I ₆					
11	46 — GND					
12	45 – I ₇					
13	44 — I ₈					
14	43 — I ₉					
15	4 2 — I _{1 0}					
16	41 - I ₁₁					
17	40 l ₁₂					
18	39 — GND					
19	38 — I ₁₃					
20	37 – I ₁₄					
21	36 — I ₁₅					
22	35 – V _{CC}					
23	34 — I ₁₆					
24	33 – I ₁₇					
25	32 — GND					
26	31 – I ₁₈					
27	30 – I ₁₉					
28	29 — OE ₃					
	1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27					

Truth Tables

	Inputs		Outputs
OE ₁	0E2	I ₀ —I ₉	0 ₀ –0 ₉
L	L	L	L
L	L	н	н
н	Х	Х	z
Х	Н	Х	Z
	Inputs		Outputs
	inputs		Outputs
OE ₃		I ₀ —I ₉	O ₁₀ -O ₁₉
OE ₃		l₀−l9 L	-
-	OE ₄		O ₁₀ –O ₁₉
L	OE ₄	L	0 ₁₀ -0 ₁₉ L

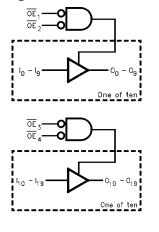
H = HIGH Voltage Level

 $\begin{array}{l} \mbox{Lowel} \label{eq:lowel} \\ \mbox{X} = \mbox{Immaterial (HIGH or LOW, inputs may not float)} \\ \mbox{Z} = \mbox{High Impedance} \end{array}$

Functional Description

The 74VCX162827 contains twenty non-inverting buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of each other. The control pins may be shorted together to obtain full 20-bit operation. The 3-STATE outputs are controlled by Output Enable (\overline{OE}_n) inputs. When \overline{OE}_1 , and \overline{OE}_2 are LOW, $O_0 - O_{10}$ are in the 2-state mode. When either \overline{OE}_1 or $\overline{\text{OE}}_2$ are HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs. The same applies for byte two with $\overline{\text{OE}}_3$ and $\overline{\text{OE}}_4.$

Logic Diagrams



Absolute Maximum Ratings(Note 2)

Recommended Operating

Supply Voltage (V _{CC})	-0.5V to +4.6V
DC Input Voltage (VI)	-0.5V to +4.6V
Output Voltage (V _O)	
Outputs 3-STATE	-0.5V to +4.6V
Outputs Active (Note 3)	–0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) $V_I < 0V$	–50 mA
DC Output Diode Current (I _{OK})	
V _O < 0V	–50 mA
V _O > V _{CC}	+50 mA
DC Output Source/Sink Current	
(I _{OH} /I _{OL})	±50 mA
DC V _{CC} or GND Current per	
Supply Pin (I _{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	$-65^{\circ}C$ to $+150^{\circ}C$

0
1.4V to 3.6V
-0.3V to +3.6V
0V to V _{CC}
0.0V to 3.6V
±12 mA
±8 mA
±3 mA
±1 mA
$-40^{\circ}C$ to $+85^{\circ}C$
10 ns/V

74VCX162827

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_{O} Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
VIH	HIGH Level Input Voltage		2.7 - 3.6	2.0		
			2.3 - 2.7	1.6		V
			1.65 - 2.3	$0.65 \times V_{CC}$		v
			1.4 - 1.6	$0.65 \times V_{CC}$		
V _{IL}	LOW Level Input Voltage		2.7 - 3.6		0.8	
			2.3 - 2.7		0.7	v
			1.65 - 2.3		$0.35 \times V_{\rm CC}$	v
			1.4 - 1.6		$0.35 \times V_{\rm CC}$	
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.7 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -6 \text{ mA}$	2.7	2.2		
		I _{OH} = -8 mA	3.0	2.4		
		$I_{OH} = -12 \text{ mA}$	3.0	2.2		
		$I_{OH} = -100 \ \mu A$	2.3 - 2.7	V _{CC} - 0.2		
		$I_{OH} = -4 \text{ mA}$	2.3	2.0		V
		$I_{OH} = -6 \text{ mA}$	2.3	1.8		v
		I _{OH} = -8 mA	2.3	1.7		
		$I_{OH} = -100 \ \mu A$	1.65 - 2.3	V _{CC} - 0.2		
		$I_{OH} = -3 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \ \mu A$	1.4 - 1.6	V _{CC} - 0.2		
		$I_{OH} = -1 \text{ mA}$	1.4	1.05		

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DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7 - 3.6		0.2	
		I _{OL} = 6 mA	2.7		0.4	
		I _{OL} = 8 mA	3.0		0.55	
		I _{OL} = 12 mA	3.0		0.8	
		I _{OL} = 100 μA	2.3 - 2.7		0.2	
		$I_{OL} = 6 \text{ mA}$	2.3		0.4	V
		I _{OL} = 8 mA	2.3		0.6	
		I _{OL} = 100 μA	1.65 - 2.3		0.2	
		$I_{OL} = 3 \text{ mA}$	1.65		0.3	
		I _{OL} = 100 μA	1.4 - 1.6		0.2	
		I _{OL} = 1 mA	1.4		0.35	
I _I	Input Leakage Current	$0 \le V_1 \le 3.6V$	1.4 - 3.6		±5.0	μΑ
I _{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.4 - 3.6		±10.0	
		$V_I = V_{IH} \text{ or } V_{IL}$	1.4 - 3.0		±10.0	μA
I _{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10.0	μΑ
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.4 - 3.6		20.0	
		$V_{CC} \leq (V_{I}, V_{O}) \leq 3.6V \text{ (Note 5)}$	1.4 - 3.6		±20.0	μA
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 6)

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Figure
Symbol		Conditions	(V)	Min	Max	Units	Number
t _{PHL}	Propagation Delay	$C_L = 30 \text{ pF}, \text{ R}_L = 500\Omega$	3.3 ± 0.3	0.8	3.4		
t _{PLH}			2.5 ± 0.2	1.0	4.1		Figures 1, 2
			1.8 ± 0.15	1.5	8.2	ns	1, 2
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	16.4		Figures 5, 6
t _{PZL}	Output Enable Time	$C_L = 30 \text{ pF}, \text{ R}_L = 500\Omega$	3.3 ± 0.3	0.8	4.3		
t _{PZH}			2.5 ± 0.2	1.0	5.9		Figures 1, 3, 4
			1.8 ± 0.15	1.5	9.8	ns	1, 0, 4
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	19.6		Figures 5, 7, 8
t _{PLZ}	Output Disable Time	$C_L = 30 \text{ pF}, \text{ R}_L = 500\Omega$	3.3 ± 0.3	0.8	4.3		
t _{PHZ}			2.5 ± 0.2	1.0	4.9		Figures 1, 3, 4
			1.8 ± 0.15	1.5	8.8	ns	1, 0, 4
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	17.6		Figures 5, 7, 8
t _{OSHL}	Output to Output Skew	$C_L = 30 \text{ pF}, \text{ R}_L = 500\Omega$	3.3 ± 0.3		0.5		
t _{OSLH}	(Note 7)		2.5 ± 0.2		0.5	ns	
			1.8 ± 0.15		0.75	115	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1		1.5		

Note 6: For $C_L = 50 PF$, add approximately 300 ps to the AC maximum specification.

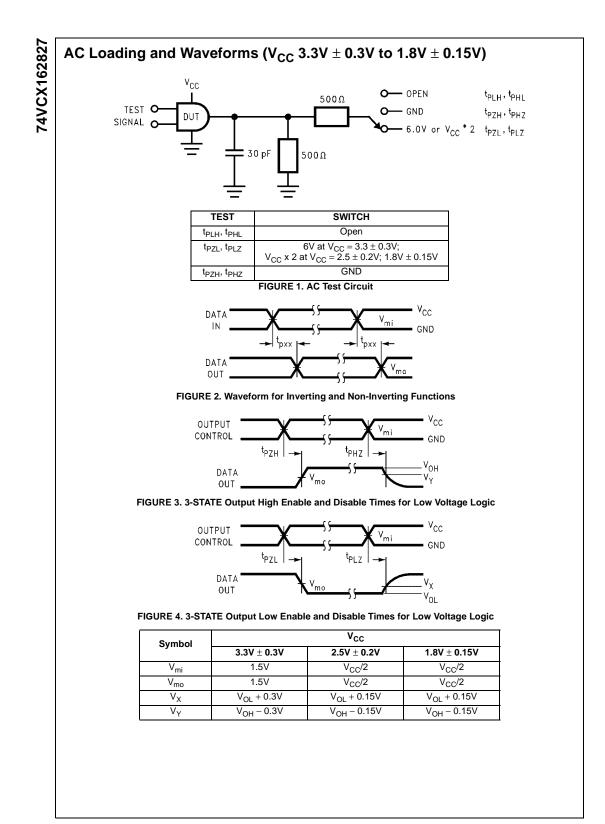
Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Symbol Pa	Parameter	Parameter Conditions	V _{cc}	$T_A = +25^{\circ}C$	Units
Symbol	Parameter	Conditions	(V)	Typical	
OLP	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.15	
			2.5	0.25	V
			3.3	0.35	
DLV	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.15	
			2.5	-0.25	V
			3.3	-0.35	
OHV	Quiet Output Dynamic Valley VOH	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.55	
			2.5	2.05	V
			3.3	2.65	

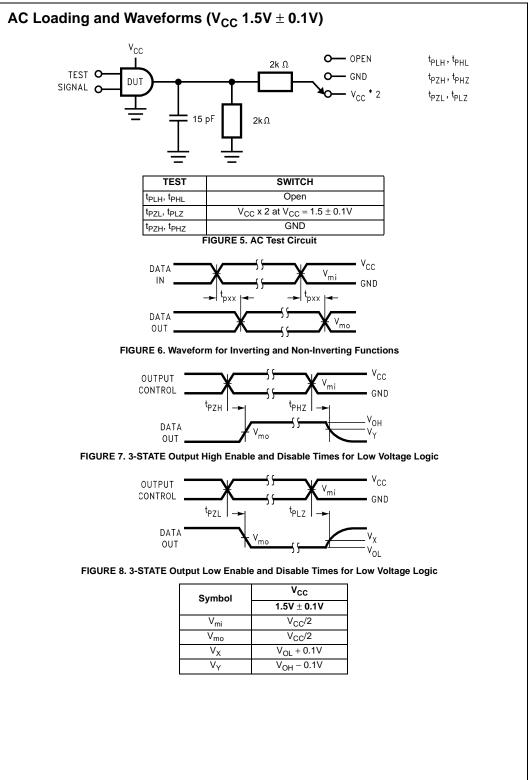
Capacitance

Symbol	Parameter	Conditions	$\textbf{T}_{\textbf{A}}=+\textbf{25}^{\circ}\textbf{C}$	Units
	i didiliciti	Conditions	Typical	
CIN	Input Capacitance	V_{CC} = 1.8, 2.5V or 3.3V, V_{I} = 0V or V_{CC}	6.0	pF
C _{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC} , $V_{CC} = 1.8V$, 2.5V or 3.3V	7.0	pF
C _{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC} , f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20.0	pF

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